

NCE N-Channel Enhancement Mode Power MOSFET

Description

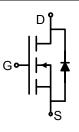
The NCE0202VA uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

- V_{DS} = 200V, I_{D} =2A $R_{DS(ON)}$ < 580mΩ @ V_{GS} =10V (Typ:520mΩ)
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Excellent package for good heat dissipation

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply



Schematic diagram



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
0202VA	NCE0202VA	TO-126	-	-	-

Absolute Maximum Ratings (T_A=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	200	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	I _D	2	Α
Drain Current-Pulsed (Note 1)	I _{DM}	8	Α
Maximum Power Dissipation	P _D	3	W
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 150	$^{\circ}$ C

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ hetaJA}$	41.7	°C/W

Electrical Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	200	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =200V,V _{GS} =0V	-	-	1	μΑ



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NCE0202VA

Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V		-	±100	nA	
On Characteristics (Note 3)							
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250µA	1.2	1.7	2.5	V	
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =2A	-	520	580	mΩ	
Forward Transconductance	g FS	V _{DS} =15V,I _D =2A	-	8	-	S	
Dynamic Characteristics (Note4)	·						
Input Capacitance	C _{lss}	V _{DS} =25V,V _{GS} =0V,	-	580	-	PF	
Output Capacitance	C _{oss}	V _{DS} -23V,V _{GS} -0V, F=1.0MHz	-	90	-	PF	
Reverse Transfer Capacitance	C _{rss}	F-1.0WI1Z	-	3	-	PF	
Switching Characteristics (Note 4)	·						
Turn-on Delay Time	t _{d(on)}		-	10	-	nS	
Turn-on Rise Time	t _r	V_{DD} =100V, R_L =15 Ω	-	12	-	nS	
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10 V , R_{G} =2.5 Ω	-	15	-	nS	
Turn-Off Fall Time	t _f		-	15	-	nS	
Total Gate Charge	Qg	V =100V/I =2A	-	12		nC	
Gate-Source Charge	Q_{gs}	V_{DS} =100V, I_{D} =2A, V_{GS} =10V	-	2.5	-	nC	
Gate-Drain Charge	Q _{gd}	VGS-10V	-	3.8	-	nC	
Drain-Source Diode Characteristics							
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =2A	-	-	1.2	V	
Diode Forward Current (Note 2)	Is				2	Α	

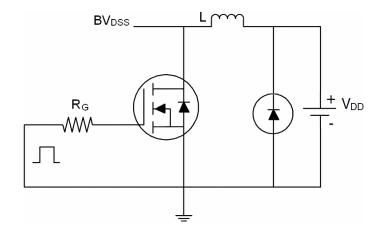
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- **3.** Pulse Test: Pulse Width ≤ 300μ s, Duty Cycle ≤ 2%.
- $\textbf{4.} \ \textbf{Guaranteed by design}, \ \textbf{not subject to production}$

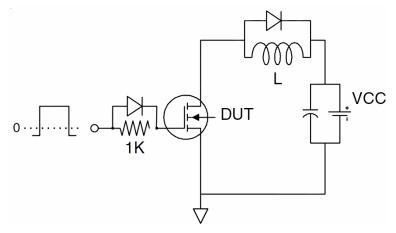
Pb-Free Product

Test Circuit

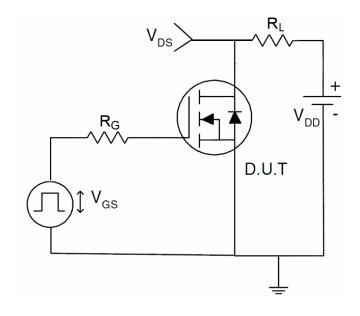
1) E_{AS} test circuit



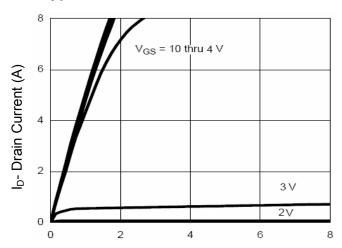
2) Gate charge test circuit



3) Switch Time Test Circuit

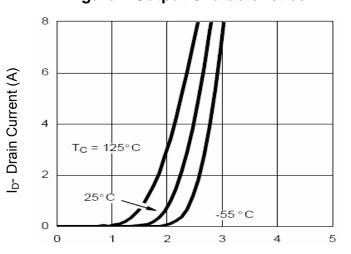


Typical Electrical and Thermal Characteristics (Curves)



Vds Drain-Source Voltage (V)

Figure 1 Output Characteristics



Vgs Gate-Source Voltage (V)
Figure 2 Transfer Characteristics

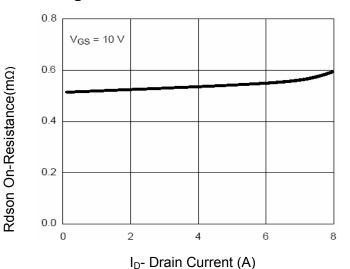
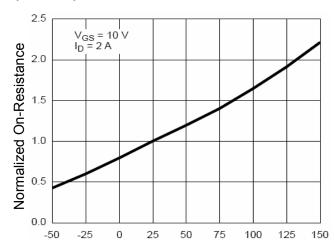
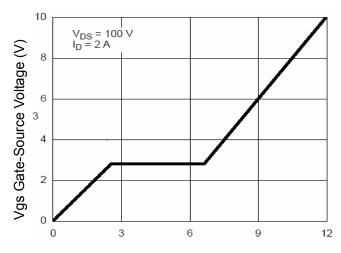


Figure 3 Rdson- Drain Current

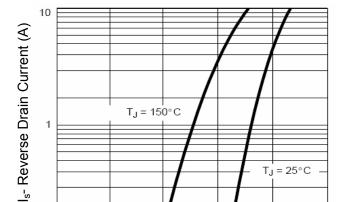


T_J-Junction Temperature(°C)

Figure 4 Rdson-JunctionTemperature



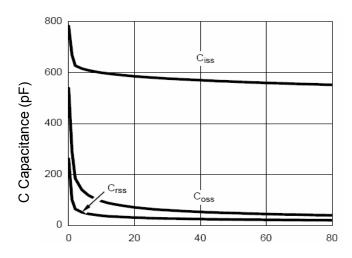
Qg Gate Charge (nC)
Figure 5 Gate Charge



Vsd Source-Drain Voltage (V)

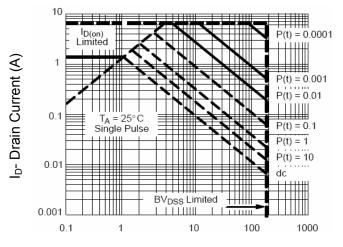
0.0

Figure 6 Source- Drain Diode Forward



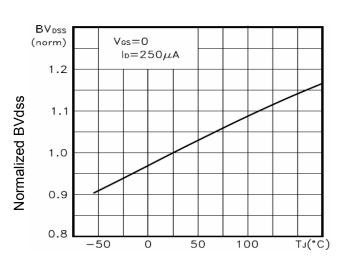
Vds Drain-Source Voltage (V)

Figure 7 Capacitance vs Vds



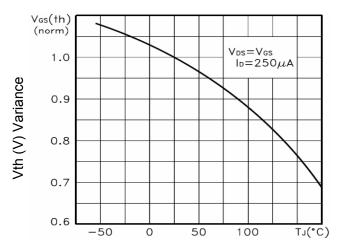
Vds Drain-Source Voltage (V)

Figure 8 Safe Operation Area



 T_J -Junction Temperature($^{\circ}$ C)

Figure 9 BV_{DSS} vs Junction Temperature



 T_J -Junction Temperature($^{\circ}\mathbb{C}$)

Figure 10 V_{GS(th)} vs Junction Temperature

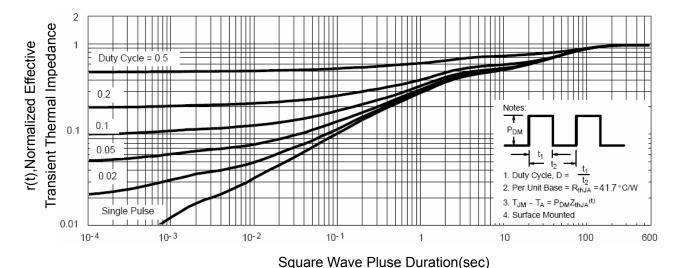
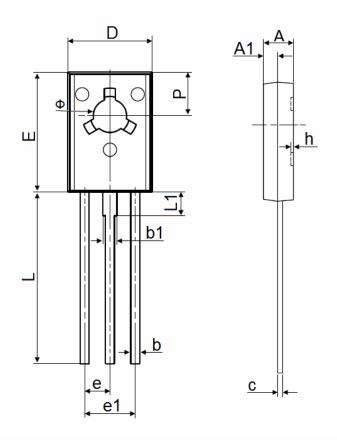


Figure 11 Normalized Maximum Transient Thermal Impedance

TO-126 Package Information



Symbol	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	2.500	2.900	0.098	0.114	
A1	1.100	1.500	0.043	0.059	
b	0.660	0.860	0.026	0.034	
b1	1.170	1.370	0.046	0.054	
С	0.450	0.600	0.018	0.024	
D	7.400	7.800	0.291	0.307	
E	10.600	11.000	0.417	0.433	
е	2.290	TYP	0.090 TYP		
e1	4.480	4.680	0.176	0.184	
h	0.000	0.300	0.000	0.012	
L	15.300	15.700	0.602	0.618	
L1	2.100	2.300	0.083	0.091	
Р	3.900	4.100	0.154	0.161	
Ф	3.000	3.200	0.118	0.126	

Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- $5. \ Controlling \ dimension \ is \ millimeter, \ converted \ inch \ dimensions \ are \ not \ necessarily \ exact.$

Pb-Free Product

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